## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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## FIRST INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR 1.56

Honorable Commissioner of Patents and Trademarks Washington, D.C. 20231

Sir:

Pursuant to 37 CFR 1.56, 1.97, and 1.98, Applicants submit the attached form PTO-1449 (modified). This application is a continuation-in-part application of Serial Nos. 09/941,440 and 10/008,959. Since all of the documents listed on the enclosed form PTO-1449 (modified) were previously cited to or by the USPTO in the prior applications, under the provisions of 37 C.F.R. 1.98(d), copies of the listed documents are not enclosed.

Respectfully submitted,

John P. Taylor

Attorney for Applicants Registration No. 22,369

Date: July 7, 2003

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Mailing Address:

Sandeep Jaggi, Chief Intellectual Property Counsel Intellectual Property Law Department LSI Logic Corporation 1551 McCarthy Blvd., Mail Stop D-106 Milpitas, CA 95035

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	AA	5,874,367	2/23/99	Dobson	438	787				
	AB	6,028,015	2/22/00	Wang et al.	438	789		3/29/9	9	
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	AH	5,915,203	6/22/99	Sengupta et al.	438	669	_	6/10/9	7	
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  - AS Dobson, C.D., et al., "Advanced SiO<sub>2</sub> Planarization Using Silane and H<sub>2</sub>O<sub>2</sub>", Semiconductor International, December 1994, pp. 85-88.
- AT McClatchie, S., et al., "Low Dielectric Constant Oxide Films Deposited Using CVD Techniques", 1998 Proceedings Fourth International DUMIC Conference, February 16-17, 1998, pp. 311-318.

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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.

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	ва	6,221,775	4/24/01	Ference et al.	438	691		9/24/98				
	BB	5,854,126	12/98	Tobben et al.	438	626						
	ВC	6,207,570	3/01	Mucha	438	692						
	BD	5,989,998	11/23/99	Sugahara et al.								
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<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.

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	CA	5,904,154	5/18/99	Chien et al.	134	1.2	7/24/97		
	СВ	5,882,489	3/16/99	Bersin et al.	204	192.35	4/26/96	<del></del>	
	CC	5,858,879	1/12/99	Chao et al.	438	725	6/6/97		
	CD	3,012,861	12/12/61	Ling	23	223.5	1/15/60		
	CE	3,178,392	4/13/65	Kriner	260	46.5	4/9/62		
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	CG	3,920,865	11/18/75	Läufer et al.	427	220	4/6/72		
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	DA	6,066,574	5,23/00	You et al.	438	781		11/6/98			
	DB	6,051,477	4/18/00	Nam	438	404		10/22/96			
	DC	6,025,263	2/15/00	Tsai et al.	438	624		9/11/97			
	DD	5,939,763	8/17/99	Hao et al.	257	411		9/5/96			
	DE	5,864,172	1/26/99	Kapoor et al.	257	634		8/13/96			
	DF	5,688,724	11/18/97	Yoon et al.	437	235		12/23/94			
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	DS	Silica Film	s for Inter al Meeting,	al., "Chemical Vapor clayer Dielectric App <u>Electrochemical Soc</u>	olication"	, 1999 J	oin	.t			
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	EA	5,628,871	5/13/97	Shinagawa	438	514	6/24/94			
	EB	6,153,524	11/28/00	Henley et al.	438	691	7/28/98			
	EC	6,051,073	4/18/00	Chu et al.	118	723	6/3/98			
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	EJ	6,043,167	3/28/2000	Lee et al.	438	789	10/10/97			
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